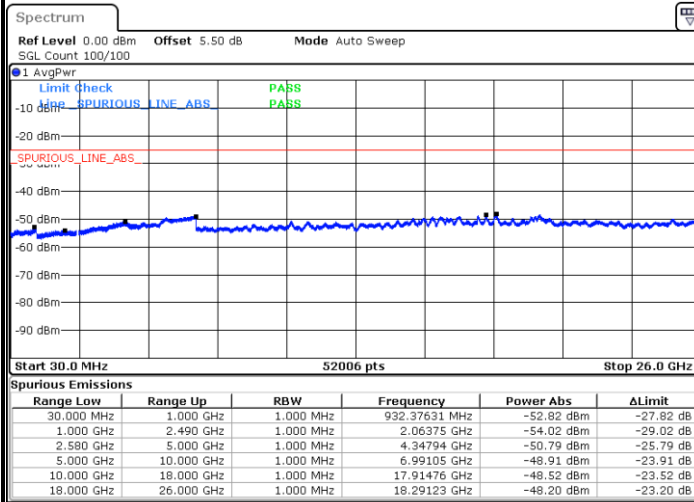




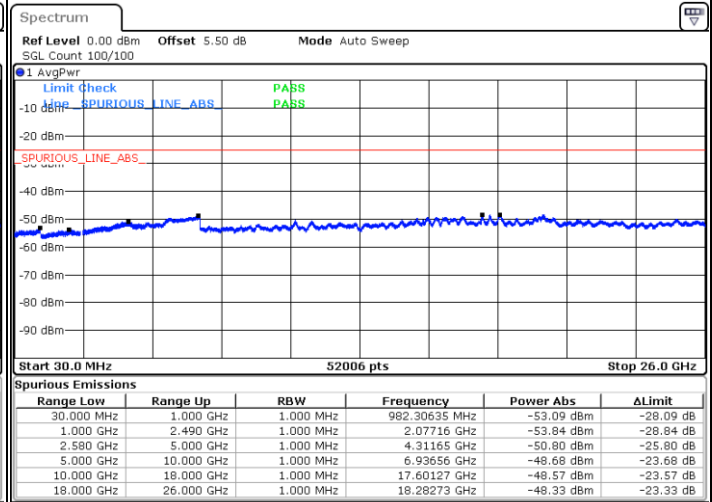
LTE Band 7 / 10MHz

Middle Channel / QPSK



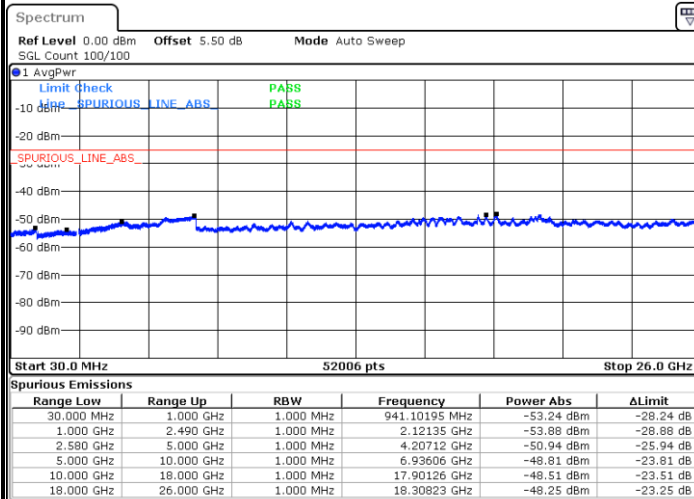
Date: 30 SEP 2018 22:43:08

Middle Channel / 16QAM



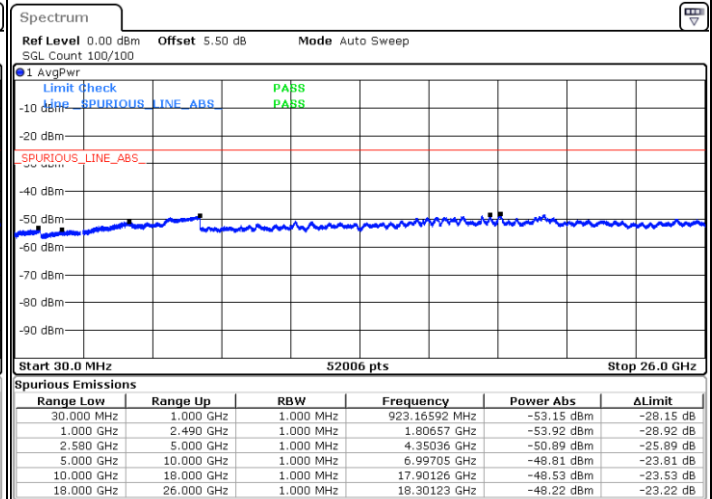
Date: 30 SEP 2018 22:44:01

Highest Channel / QPSK



Date: 30 SEP 2018 22:51:45

Highest Channel / 16QAM

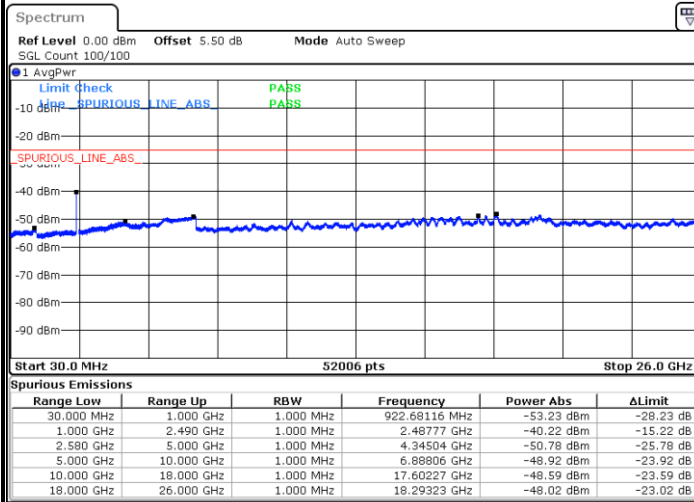


Date: 30 SEP 2018 22:50:52



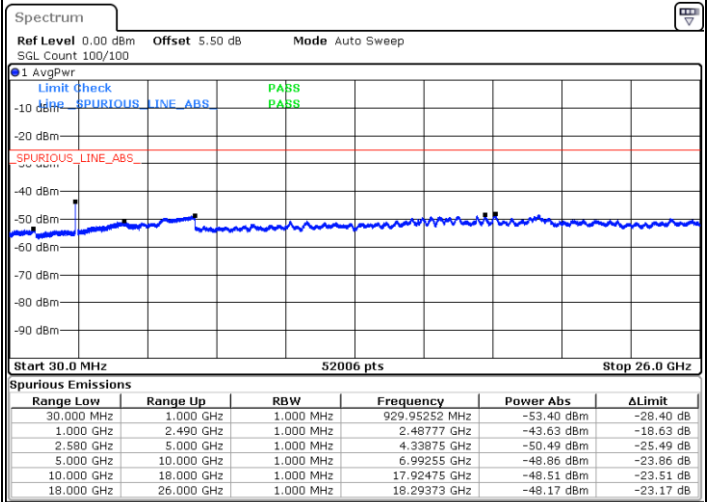
LTE Band 7 / 15MHz

Lowest Channel / QPSK



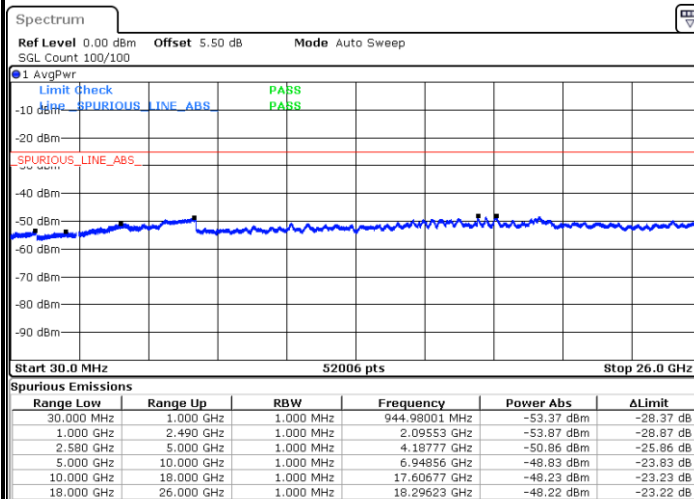
Date: 30 SEP 2018 22:54:12

Lowest Channel / 16QAM



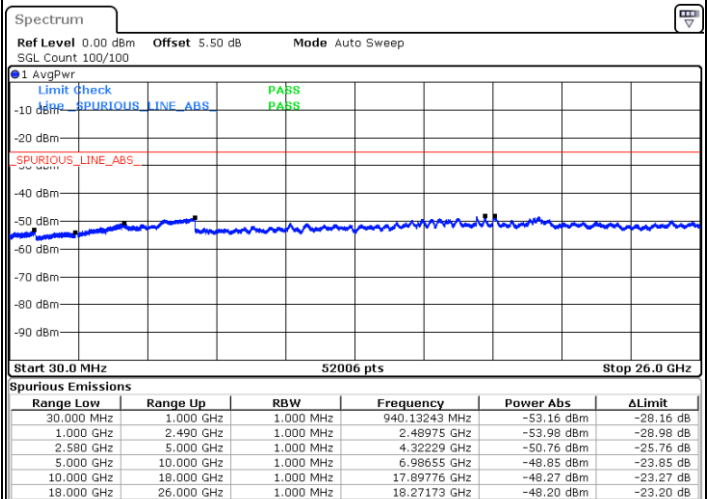
Date: 30 SEP 2018 22:53:18

Middle Channel / QPSK



Date: 30 SEP 2018 22:55:05

Middle Channel / 16QAM

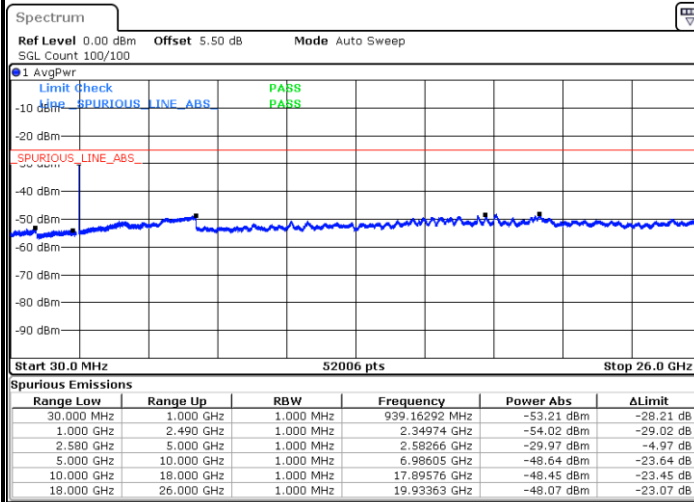


Date: 30 SEP 2018 22:55:58



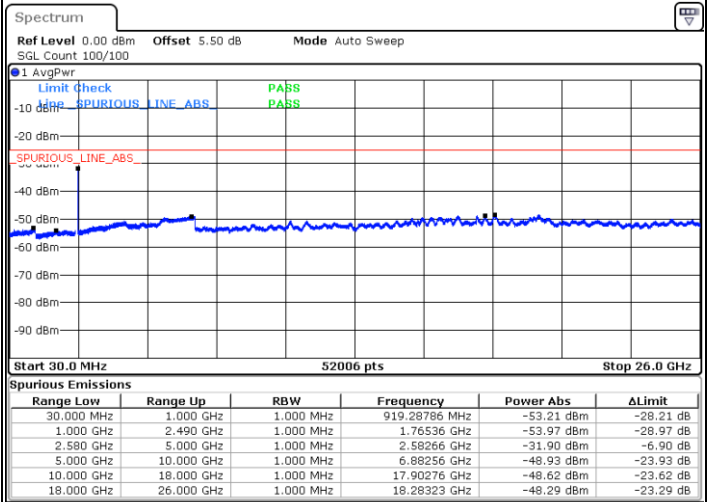
LTE Band7 / 15MHz

Highest Channel / QPSK



Date: 30 SEP 2018 23:03:42

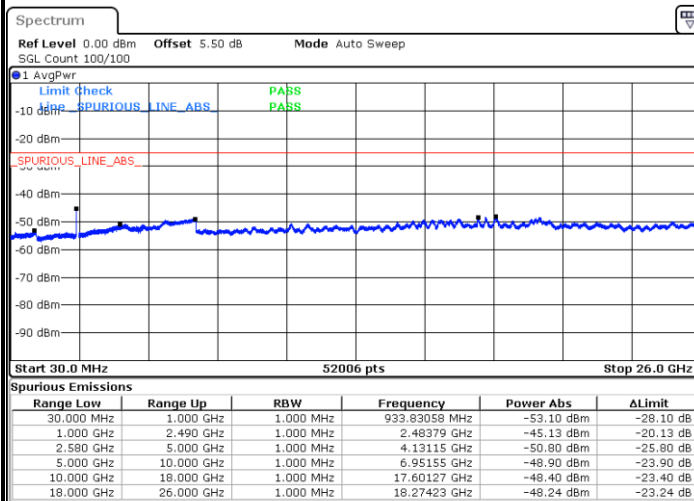
Highest Channel / 16QAM



Date: 30 SEP 2018 23:02:49

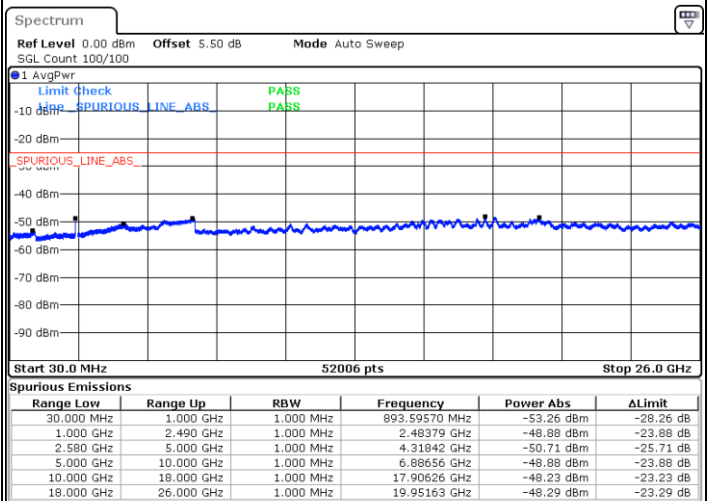
LTE Band 7 / 20MHz

Lowest Channel / QPSK



Date: 30 SEP 2018 23:06:09

Lowest Channel / 16QAM

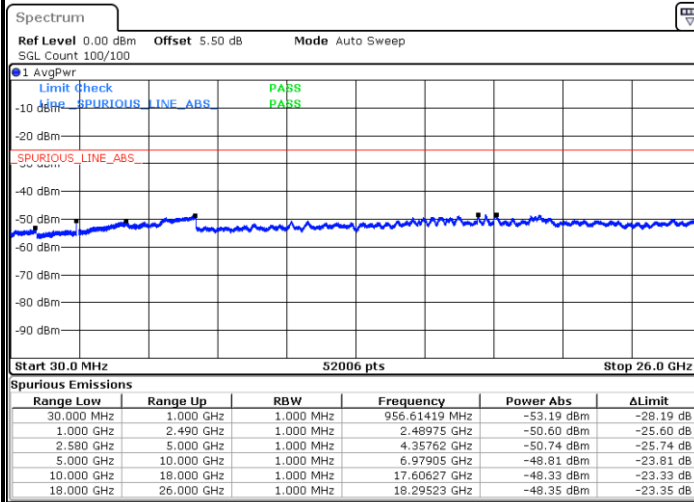


Date: 30 SEP 2018 23:05:15



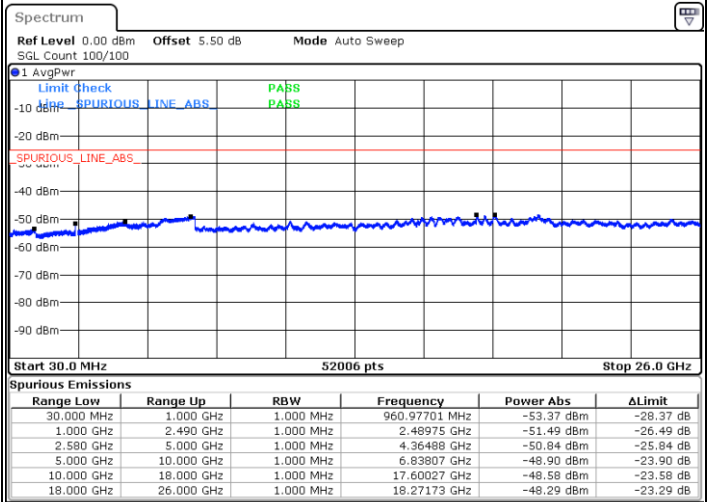
LTE Band 7 / 20MHz

Middle Channel / QPSK



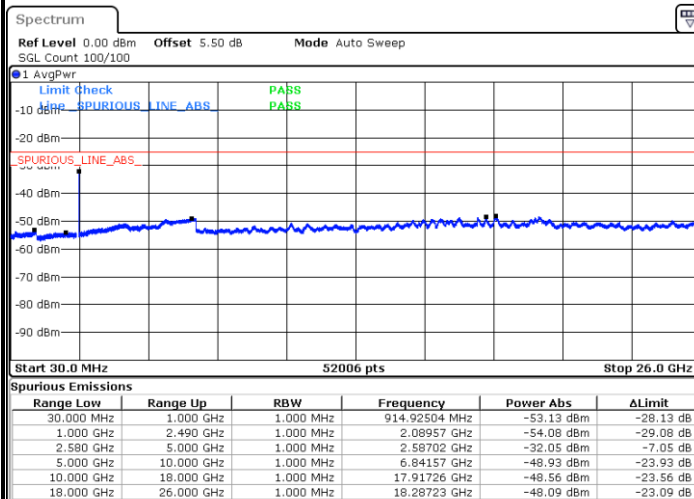
Date: 30 SEP 2018 23:07:02

Middle Channel / 16QAM



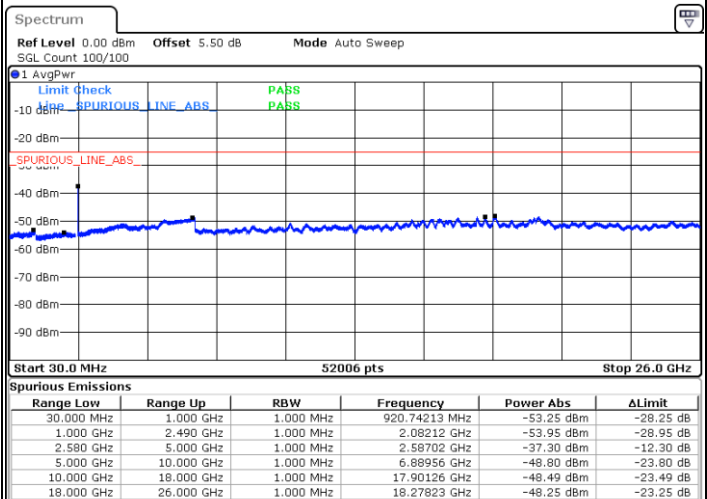
Date: 30 SEP 2018 23:07:55

Highest Channel / QPSK



Date: 30 SEP 2018 23:15:39

Highest Channel / 16QAM



Date: 30 SEP 2018 23:14:46

Frequency Stability

Test Conditions		LTE Band 7 (QPSK) / Middle Channel	Limit
Temperature (°C)	Voltage (Volt)	BW 10MHz	Note 2.
		Deviation (ppm)	Result
50	Normal Voltage	0.0023	PASS
40	Normal Voltage	0.0028	
30	Normal Voltage	0.0008	
20(Ref.)	Normal Voltage	0.0000	
10	Normal Voltage	0.0019	
0	Normal Voltage	0.0032	
-10	Normal Voltage	0.0002	
-20	Normal Voltage	0.0004	
-30	Normal Voltage	0.0020	
20	Maximum Voltage	0.0006	
20	Normal Voltage	0.0000	
20	Battery End Point	0.0027	

Note:

1. Normal Voltage =3.85 V. ; Battery End Point (BEP) =3.45 V. ; Maximum Voltage =4.35 V.
2. Note: The frequency fundamental emissions stay within the authorized frequency block.



Appendix B. Test Results of Radiated Test

Radiated Spurious Emission

LTE Band 7 / 5MHz / QPSK									
Channel	Frequency (MHz)	EIRP (dBm)	Limit (dBm)	Over Limit (dB)	SPA Reading (dBm)	S.G. Power (dBm)	TX Cable loss (dB)	TX Antenna Gain (dBi)	Polarization (H/V)
Middle	5065.68	-56.17	-25	-31.17	-77.68	-61.73	7.14	12.70	H
	7598.52	-51.18	-25	-26.18	-78.68	-54.48	8.30	11.60	H
	10131.36	-51.11	-25	-26.11	-82.83	-52.63	10.48	12.00	H
	5065.68	-57.10	-25	-32.10	-79.03	-62.66	7.14	12.70	V
	7598.52	-53.27	-25	-28.27	-80.64	-56.57	8.30	11.60	V
	10131.36	-51.64	-25	-26.64	-82.64	-53.16	10.48	12.00	V

Remark: Spurious emissions within 30-1000MHz were found more than 20dB below limit line.

LTE Band 7 / 10MHz / QPSK									
Channel	Frequency (MHz)	EIRP (dBm)	Limit (dBm)	Over Limit (dB)	SPA Reading (dBm)	S.G. Power (dBm)	TX Cable loss (dB)	TX Antenna Gain (dBi)	Polarization (H/V)
Middle	5061.18	-57.25	-25	-32.25	-78.75	-62.81	7.14	12.70	H
	7591.77	-53.02	-25	-28.02	-80.52	-56.32	8.30	11.60	H
	10122.36	-51.18	-25	-26.18	-82.90	-52.70	10.48	12.00	H
	5061.18	-56.40	-25	-31.40	-78.32	-61.96	7.14	12.70	V
	7591.77	-52.40	-25	-27.40	-79.77	-55.70	8.30	11.60	V
	10122.36	-52.16	-25	-27.16	-83.16	-53.68	10.48	12.00	V

Remark: Spurious emissions within 30-1000MHz were found more than 20dB below limit line.



LTE Band 7 / 15MHz / QPSK									
Channel	Frequency (MHz)	EIRP (dBm)	Limit (dBm)	Over Limit (dB)	SPA Reading (dBm)	S.G. Power (dBm)	TX Cable loss (dB)	TX Antenna Gain (dBi)	Polarization (H/V)
Middle	5056.68	-56.35	-25	-31.35	-77.85	-61.91	7.14	12.70	H
	7585.02	-52.34	-25	-27.34	-79.91	-55.64	8.30	11.60	H
	10113.36	-51.34	-25	-26.34	-83.05	-52.86	10.48	12.00	H
	5056.68	-55.89	-25	-30.89	-77.81	-61.45	7.14	12.70	V
	7585.02	-51.86	-25	-26.86	-79.28	-55.16	8.30	11.60	V
	10113.36	-52.05	-25	-27.05	-83.01	-53.57	10.48	12.00	V

Remark: Spurious emissions within 30-1000MHz were found more than 20dB below limit line.

LTE Band 7 / 20MHz / QPSK									
Channel	Frequency (MHz)	EIRP (dBm)	Limit (dBm)	Over Limit (dB)	SPA Reading (dBm)	S.G. Power (dBm)	TX Cable loss (dB)	TX Antenna Gain (dBi)	Polarization (H/V)
Middle	5052.18	-56.16	-25	-31.16	-77.64	-61.72	7.14	12.70	H
	7578.27	-51.54	-25	-26.54	-79.11	-54.84	8.30	11.60	H
	10104.36	-51.47	-25	-26.47	-83.20	-52.99	10.48	12.00	H
	5052.18	-56.06	-25	-31.06	-77.96	-61.62	7.14	12.70	V
	7578.27	-51.64	-25	-26.64	-79.06	-54.94	8.30	11.60	V
	10104.36	-52.10	-25	-27.10	-83.08	-53.62	10.48	12.00	V

Remark: Spurious emissions within 30-1000MHz were found more than 20dB below limit line.



Appendix D. Product Equality Declaration

Bullitt Mobile Limited

One Valpy, Valpy Street, Reading, Berkshire, England RG1 1AR

Date: 6/28/2018

Product Equality Declaration

We, Bullitt Mobile Limited, declare on our sole responsibility for the product of B35 as below:

1. The differences between present and previous are:

Object	Original Source (Dual SIMs) (Single SIM)	Second source (Dual SIMs) (Single SIM)	Remark
Receiver	R0612A24WT	PS120620HS02N	Only supplier difference

Dual SIM products are different from Single SIM products only in SIM card tray. The detailed differences are listed above.

Should you have any questions or comments regarding this matter, please have my best attention.

Sincerely yours,



Contact Person: Wayne Huang

COMPANY: Bullitt Mobile Ltd.

Tel: +886 – 2 -26278305

E-Mail: Whuang@bullitt-group.com